

12500 TI Boulevard, MS 8640, Dallas, Texas 75243

PCN#20231024001.1

Qualification of RFAB as an additional Fab site option and Assembly Site (PHI) and BOM Options for select devices Change Notification / Sample Request

Date: October 24, 2023 **To:** Newark/Farnell PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

Texas Instruments requires acknowledgement of receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance and approval of this change. If samples or additional data are required, requests must be received within **30 days** of this notification.

The changes discussed within this PCN will not take effect any earlier than the proposed first ship date on Page 3 of this notification, unless customer agreement has been reached on an earlier implementation of the change.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

For questions regarding this notice or to provide acknowledgement of this PCN, you may contact your local Field Sales Representative or the change management team.

For sample requests or sample related questions, contact your local Field Sales Representative.

Sincerely,

Change Management Team SC Business Services

20231024001.1 Attachment: 1

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, you have recently purchased these devices. The corresponding customer part number is also listed, if available.

DEVICE INA219AIDCNR

CUSTOMER PART NUMBER

null

Technical details of this Product Change follow on the next page(s).

PCN	Number	r:		202	310240	001	. 1		PCN	l Dat	e:	October 24, 2023		
Title:	Q	ation o	of RFA	AB as an additional Fab site option and Assem						seml	oly Site (PHI) and			
Title.	В	OM Op	tions f	for se	elect de	evic	es							
Customer Contact:				Change Management Team				Dept:			Quality Services			
Proposed 1 st Ship Date:					Jan 22	2, 2	024	Samp acc	ole re epte			Nov 24, 2023*		
*Sam	ple req	uests	recei	ved	after l	Nov	24, 2023 wil l	not be	sup	port	ted.			
Change Type:														
	<u> </u>				⊠ Design					Waf	afer Bump Material			
Assembly Process							Data Sheet				Waf	afer Bump Process		
\boxtimes	Assemb	oly Mat	erials				Part number of	change		⊠ Wat		fer Fab Site		
	Mechar	nical Sp	pecifica	ation			Test Site			X	Waf	er Fab Material		
	Packing	g/Shipp	ing/La	abelir	ng		Test Process				Waf	er Fab Process		
							PCN Detai	ls						

Description of Change:

Texas Instruments is pleased to announce the qualification of its RFAB fabrication facility as an additional Wafer Fab option in addition to Assembly site (PHI) and BOM options for the devices listed below.

Curre	ent Fab Site		Additional Fab site						
Current Fab Site	Process	Wafer Diameter	Additional Fab site	Process	Wafer Diameter				
AIZU	50HPA07	200mm	RFAB	50HPA07	300mm				

The die was also changed as a result of the process change to accommodate the change in Assembly technology

Construction differences are as follows:

	UTL2	PHI
Bond wire composition, diameter diameter	Au, 1.0 mil	Cu, 0.8 mil
Mount Compound	SID#PZ0037	SID#A-09
Mold Compound	SID#CZ0096	4226215
Assembly Technology	Die Down	Die Up

Reason for Change:

Supply Continuity

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
☑ No Change	⊠ No Change	⊠ No Change	⊠ No Change

Changes to product identification resulting from this PCN:

Fab Site Information:

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
AIZU	CU2	JPN	Aizuwa ka matsu- shi
RFAB	RFB	USA	Richardson

Die Rev:

(Current	New
	Die Rev [2P]	Die Rev [2P]
ſ	_	_

Assembly Site Information:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City
UTL2	NS2	THA	Bangpakong, Chachoengsao
TI Phillippines	PHI	PHL	Baguio City

Sample product shipping label (not actual product label):



MADE IN: Malaysia 2DC: 2Q: MSL 2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

5A (L)T0:3750



(1P) SN74LS07NSR (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483S12

(2P) REV: (20L) CSO: SHE (21L) CCO:USA (22L) ASO: MLA (23L) ACO: MYS

Product Affected:

INA219AIDCNR	INA219AIDCNT	INA219BIDCNR	INA219BIDCNT	
INAZIBAIDUNK	INAZIBAIDCINI	INAZISBIDCINK	INAZISDIDCINI	

Qualification Report INA219 Redbull Approve Date 28-September-2023 Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре		Test Name	Condition	Duration	Qual Device: BA218BIDCNR	Qual Device: BA2118BDCNR	QBS Reference:	QBS Reference: INAZ41AZIDSER	QES Reference: NAZALIAJEDEE	QBS Reference: BA261A6DDFR	QBS Reference: NA241ASIDDER	QBS Reference: BNA218B0QCKR01	QBS Reference: BAZ15ACQCKRCQ	QBS Reference: ADS1261BOMRHMBOL	QBS Reference: BIA190A1000EBD1	QBS Reference: BNA190A20QDERCS	QBS Reference: NA199A3CQQERO1	Q65 Reference: BA190A6000ERD1	QBS Reference: INA190A0DQDERDQ	QRS Reference	QBS Parlamence: CD3232A1YEER	QBS Reference: CD3232A1YEER	QBS Reference:	QBS Reference:	QBS Reference: CPA2175ADGKB	Q15 Reference:	QBS Reference: INAZISADOME
HAST	A2	Bissed HAST	110005W04	264 Hours		-			-		-		-	32310	-			-									
HAST	A2	Biased HAST	130CR519RH	96 Hours									3/231/0		1/77/0	1/77/0	1070				3031.0	3/231/0					1/77/0
UHAST	A3	Autoclave	121C/15psig	95 Hours										32310													
UHAST		Unbiased HAST	130CR51/RH												1/77/0	1/77/0	1/77/0				3231.0	3/231/0					1/77/0
TC		Temperature Cycle		700 Cycles																	30310	3/231/0					
TC		Temperature Cycle	-65C050C	500 Cycles	1/77/0		1/72/0	1/77/0					3/231/0	32310	1/77/0	1/77/0	1/770										1/77/0
HTSL		High Temperature Storage Life High Temperature	150C	1000 Hours				1/77/0	3/77/61		1/77/0			32310	1450	1/45/0	1450										1/770
HTSL.		Storage Life	170C	420 Hours																	30310	32310	1/770	2/154/0			
HTOL		CL (FF)	125C	1000 Hours																		1,450					
HTOL		CL (FS)	125C	1000 Hours																		1/02/0					
HTOL		CL (SS)	125C	1000 Hours 1000 Hours																		1/02/0 1/45/0				-	
HTOL		Life Test	150C	300 Hours											1/77/0	1/778	1070					1450	1070	201640			
HTOL		Life Test	125C	1000 Hours				1/77/0	1/77/0		1/77/0		20210	32310	arriva .	2774	20700						Limi	21540			1/77/0
HTOL		Life Test	140C	480 Hours																	1/77/0	2/1540					
ELFR		ELFR	125C	48 Hours																	1/10000	2/2000/0					
ELFR	82	Early Life Failure Rate	125C	48 Hours									3/2400/0										1/1000/0	2/2000/0			
SD	C3	PB Solderability	Steam Age, 8 Hours											1/15/0	1/15/0	1/150	1050										
SD	C3	PB Solderability	Precondition w155C Dry Bake (4 hrs vi-15 minutes)											1/15/0	1/15/0	1/150	1050										
SD	сз	Pt-free Scidenbilty	Precondition w155C Dry																		3660	2/66/0					
SD		P2-Free Sciderability	e/- 15 minutes)											1/15/0	1/15/0	1/15/0	1050										-
SD	C3	P2-free Suiderability	Steam Age, 8 Hours											1/15/0	1/15/0	1/150	1850										
PD		Physical Dimensions	mechanical drawing)																		3600	3800	1000	2/45/0			
PD		Physical Dimensions	Cpk>1.67	-										3/30/0	1/10/0	1/33/0	1500										
ESD	E2	ESD CDM	-	250 Vols	100		1/3/0	1/3/0	100	1/3/0	100										3912			2/6/0			130
ESD		ESD CDM	-	350 Volts 200 Volts													-	-				390	1/5/0			-	
ESD		ESD CDM	-	1000 Velts				-					-	1/9/0			-	-				anW0			1/3/0	100	
ESD		ESD CDM	-	1500 Vels								100		250	1/3/0	100	130	130	100						1/3/0	180	
ESD		ESD LEM		1000 Vota	100			100	100	100	100										3/9/0	390		260			100
ESD		ESD HBM		1500 Vota	-			-	-		-												1/0/0				-
ESD		ESD HBM		2000 Vots										1/3/0													
ESD		ESD HBM		4000 Vots								100			1/3/0	100	1/3/0	130	100							100	
LU	E4	LU	Per JESD78																		3/9/0	390					
LU	E4	Latch-Up	Per JESD78		130			1/3/0	100	100	100	160		1/6/0	1/6/0	160	180	160	160				180	2/12/0		100	1/3/0
CHAR	ES	Electrical Distributions	Cpk>1.67 floom, hot, and cold									3900		3/90/0	1000	1/30/0	1000	1300	1,900								
CHUR	ES	Electrical Characterization	Par Datasheet Parameters		1000	1990	1860	1000	1/90/0	1000	1/90/0									1/30/0	1000	1/000	1000	2/00/0	100		1800
CHWR		Electrical Characterization	Min, Typ, Max Temp		1000	1990	1860	1000	1,900	1990	1,900									1980	1990	1/00/0	1000	2/60/0	100		1890
FTY	E6	Final Test Yield																							1/1/0	10.0	
- 086																											

QBS: Qual By Similarity
 Qual Device INAZ198IDCNR is qualified at MSL1 260C

1] Incomplete deep trench etching that will be screen out by MP and SQS.

[2] Weiver from CF

For questions regarding this notice, e-mails can be sent to the Change Management team or your local Field Sales Representative.

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Preconditioning was performed for Autoclave, Unbiased HAST, THEMESISED HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
 The following are equivalent HTCL options based on an activation energy of 0.74V : 125C/12 Hours, 140CH80 Hours, 250C/300 Hours, and 155C/340 Hours

The following are equivalent HTSL options based on an activation energy of 0.74Y : 150Ctk Hours, and 170CH20 f
 The following are equivalent firmp Cycle options per 353CH7 : -55Ch25C700 Cycles and -65Cl250C500 Cycles

Quality and Environmental data is available at TTs external Web site: <u>2011/2000</u>. TI Qualification ID: R-NPD-2303-075